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APPLICATION NO. FILING DATE		FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO. 5083	
09/852,672 05/11/2001		05/11/2001	Hideomi Suzawa	12732-038001		
26171	7590	06/03/2003				
FISH & RICHARDSON P.C.			EXAMINER			
1425 K STREET, N.W. 11TH FLOOR WASHINGTON, DC 20005-3500			SIMKOVIC	C, VIKTOR		
			ART UNIT	PAPER NUMBER		
				2812		
				DATE MAILED: 06/03/2003	<b>,</b>	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)
	09/852,672	SUZAWA ET AL.
Office Action Summary	Examiner	Art Unit
	Viktor Simkovic	2812
The MAILING DATE of this communication a	<u> </u>	with the correspondence address
Period for Reply		
A SHORTENED STATUTORY PERIOD FOR REP THE MAILING DATE OF THIS COMMUNICATION  - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a re - If NO period for reply is specified above, the maximum statutory perions - Failure to reply within the set or extended period for reply will, by state - Any reply received by the Office later than three months after the mail earned patent term adjustment. See 37 CFR 1.704(b).  Status	I.  1.136(a). In no event, however, may eply within the statutory minimum of od will apply and will expire SIX (6) No ute, cause the application to become	v a reply be timely filed thirty (30) days will be considered timely IONTHS from the mailing date of this communication.
1) Responsive to communication(s) filed on 20	<u>0 March 2003</u> .	
2a) ☐ This action is <b>FINAL</b> . 2b) ☑ 3	This action is non-final.	
3) Since this application is in condition for allocal closed in accordance with the practice under		
Disposition of Claims		
4) Claim(s) 9-39 is/are pending in the applicati		
4a) Of the above claim(s) is/are withdr	rawn from consideration.	
5) Claim(s) <u>28,32-34,38 and 39</u> is/are allowed.		
6) Claim(s) <u>9-27,29-31 and 35-37</u> is/are rejecte	ed.	
7) Claim(s) is/are objected to.		
8) Claim(s) are subject to restriction and Application Papers	/or election requirement.	
9) The specification is objected to by the Examin	ner.	
10) The drawing(s) filed on is/are: a) acc		v the Examiner.
Applicant may not request that any objection to		
11) The proposed drawing correction filed on		
If approved, corrected drawings are required in		
12) The oath or declaration is objected to by the I	Examiner.	
Priority under 35 U.S.C. §§ 119 and 120		
13) Acknowledgment is made of a claim for fore	ign priority under 35 U.S.	C. § 119(a)-(d) or (f).
a)⊠ All b) Some * c) None of:		
1. Certified copies of the priority docume	ents have been received.	
2. Certified copies of the priority docume	nts have been received in	Application No
Copies of the certified copies of the prapplication from the International Example       See the attached detailed Office action for a limit	Bureau (PCT Rule 17.2(a)	)).
14) Acknowledgment is made of a claim for dome	•	
a) The translation of the foreign language p	provisional application has	s been received.
15) Acknowledgment is made of a claim for dome Attachment(s)	sale priority under 35 U.S.	.C. 33 120 and/01 121.
1) Notice of References Cited (PTO-892)	4) T Intervi	ew Summary (PTO-413) Paper No(s)
<ul> <li>1) Notice of References Cited (PTO-992)</li> <li>2) Notice of Draftsperson's Patent Drawing Review (PTO-948)</li> <li>3) Information Disclosure Statement(s) (PTO-1449) Paper No(s</li> </ul>	5) Notice	of Informal Patent Application (PTO-152)
		<del> </del>

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#### **DETAILED ACTION**

## Double Patenting

The nonstatutory double patenting rejection is based on a judicially created doctrine grounded in public policy (a policy reflected in the statute) so as to prevent the unjustified or improper timewise extension of the "right to exclude" granted by a patent and to prevent possible harassment by multiple assignees. See *In re Goodman*, 11 F.3d 1046, 29 USPQ2d 2010 (Fed. Cir. 1993); *In re Longi*, 759 F.2d 887, 225 USPQ 645 (Fed. Cir. 1985); *In re Van Ornum*, 686 F.2d 937, 214 USPQ 761 (CCPA 1982); *In re Vogel*, 422 F.2d 438, 164 USPQ 619 (CCPA 1970);and, *In re Thorington*, 418 F.2d 528, 163 USPQ 644 (CCPA 1969).

A timely filed terminal disclaimer in compliance with 37 CFR 1.321(c) may be used to overcome an actual or provisional rejection based on a nonstatutory double patenting ground provided the conflicting application or patent is shown to be commonly owned with this application. See 37 CFR 1.130(b).

Effective January 1, 1994, a registered attorney or agent of record may sign a terminal disclaimer. A terminal disclaimer signed by the assignee must fully comply with 37 CFR 3.73(b).

Claims 9 and 10-17, 29, 35 are rejected under the judicially created doctrine of double patenting over claim 8 of allowed U.S. Pub. 2002/0066705 (App. No. 09/852,282, which has not been assigned a patent number yet) since the claims, if allowed, would improperly extend the "right to exclude" already granted in the patent.

The subject matter claimed in the instant application is fully disclosed in the patent and is covered by the patent since the patent and the application are claiming common subject matter, as follows: While the present application does not claim using dry etching to form the electrodes, this only makes the present claim 9 broader in scope. And though claim 8 of Application No. 09/852,282 does not claim forming a high concentration impurity region in the sixth step and a low concentration impurity region in the eighth step, this is taught in paragraph 40 of Application No. 09/852,282. With

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regard to dependent claims 10-17, 29, 35, these contain no allowable subject matter as these limitations are discussed in the specification of Application No. 09/852,282

Claims 18-19 and 20-27, 30-31, 36-37 are rejected under the judicially created doctrine of double patenting over claim 10 of allowed U.S. Pub. 2002/0016028 (App. No. 09/873,334, which has not been assigned a patent number yet) since the claims, if allowed, would improperly extend the "right to exclude" already granted in the patent. The subject matter claimed in the instant application is fully disclosed in the patent and is covered by the patent since the patent and the application are claiming common subject matter, as follows: Claim 19 of the present application only omits one step, and forms both impurity regions with one step, whereas in claim 10 of Application No. 09/873,334 they are formed in two steps. However, though the third electrode is formed between the two impurity forming steps in claim 10 of Application No. 09/873,334, the width of the second conductive layer, which is used as the mask, does not change, and thus the switching of the order of the steps is irrelevant and has no patentable significance. With regard to dependent claims 20-27, 30-31, 36-37, these contain no allowable subject matter as these limitations are discussed in the specification of Application No. 09/873,334.

Furthermore, there is no apparent reason why applicant was prevented from presenting claims corresponding to those of the instant application during prosecution of the application which matured into a patent. See *In re Schneller*, 397 F.2d 350, 158 USPQ 210 (CCPA 1968). See also MPEP § 804.

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## Allowable Subject Matter

Claims 28 and 33 and the dependent claims 32, 34, 38-39 are allowed.

The following is a statement of reasons for the indication of allowable subject matter: Prior art of record fails to teach the method of forming a semiconductor device that includes the steps of laminating first and second conductive films on the substrate, followed by the formation of a conductive layer, which is used as a mask to form a high concentration impurity region, followed by an etching of the first conductive film to form an electrode.

### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Viktor Simkovic whose telephone number is 703-308-6170. The examiner can normally be reached on Mon - Fri, 9:00 - 6:00, except every other Friday. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, John Niebling can be reached on 703-308-3325. The fax phone numbers for the organization where this application or proceeding is assigned are 703-308-7722 for regular communications and 703-308-7722 for After Final communications. Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-1782.

Viktor Simkovic May 22, 2003 John E. Niebling

Supervisery Patent Examiner

Technishow Genter 2800



Sheet 1

Substitute Form PTO-1449 (Modified)

U.S. Department of Commerce Patent and Trademark Office

Attorney's Docket No. 12732-038001

Application No. 09/852,672

Information Disclosure Statement

by Applicant
(Use several sheets if necessary)

Applicant Hideomi Suzawa et al.

MAR 2 0 2003

(37 CFR §1.98(b))

Filing Date May 11, 2001 Group Art Unit 2812

U.S. Patent Documents							
Examiner Initja	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
6	АА	5,112,766	05/12/1992	Fujii et al.		·	07/16/1991
1	AB	5,599,741	02/04/1997	Matsumoto et al.			06/07/1995
B	AC	5,605,854	02/25/1997	Yoo			02/20/1996
1/2	AD	5,851,885	12/22/1998	Wen		6	05/30/1997
B	AE	5,973,378	10/26/1999	Ohtani		ς,	11/24/1997
19	AF	6,001,714	12/14/1999	Nakajima et al.			09/26/1997
18	AG	6,225,966	05/01/2001	Ohtani et al.			03/23/1998
W.	АН	6,271,065	08/07/2001	Miyamoto et al.			01/31/2000
19	AI	6,323,070	11/27/2001	Yamazaki			09/14/ <b>19</b> 98
1/2	AJ	6,335,290	01/01/2002	Ishida			03/29/1999
14	AK	6,365,917	04/02/2002	Yamazaki			11/16/1999
13	AL	US 2001/0041392 A1	11/15/2001	Suzawa et al.			05/11/2001
14	AM	US 2001/0052950 A1	12/20/2001	Yamazaki et al.			03/16/2001
	AN	US 2002/0000551 A1	01/03/2002	Yamazaki et al.			03/02/2001
19	AO	US 2002/0016028 A1	02/07/2002	Yamazaki et al.			06/05/2001
1	AP	US 2001/0041392 A1	11/15/2001	Suzawa et al.			05/11/2001
13	AQ	US 2001/0049197 A1	12/06/2001	Yamazaki et al.			06/04/2001
TA	AR	US 2002/0006705 A1	01/17/2002	Suzawa et al.			05/10/2001

Foreign Patent Documents or Published Foreign Patent Applications								
Examiner	Desig.	Document	Publication	Country or			Trans	slation
Initia	ID	Number	Date	Patent Office	Class	Subclass	Yes	No
11	AS	WO 87/07079	11/19/1987	WIPO				

Other Documents (include Author, Title, Date, and Place of Publication)					
Examiner	Desig.				
Initial	ID	Document			
#	AT	Hatano et al., "A Novel Self-aligned Gate-overlapped LDD Poly-Si TFT with High Reliability and Performance", IEDM Technical Digest 97, pp. 523-526			

	2
Examiner Signature	0/1
	)
	1

Date Considered

EXAMINER: Initials chation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.